Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-465-8301

Inclosure Materi	
Metal	
Overall Length:	
0.225 inches	
Terminal Length	n:
1.200 inches	
Overall Diamete	r:
0.420 inches	
Electrode Intern	ally-electrically Connected To Case:
Anode	
Mounting Metho	nd:
Terminal	
Terminal Circle	Diameter:
0.200 inches	
Features Provid	ed:
Hermetically seal	ed case
Semiconductor	Material:
Silicon	
Voltage Rating I	n Volts Per Characteristic:
300.0 forward vo	ltage, peak
Current Rating I	Per Characteristic:
2.00 amperes so	urce cutoff current absolute
Power Rating Pe	er Characteristic:
12.0 watts small-	signal input power, common-collector preset
Maximum Opera	ting Tempurature Per Measurement Point:
100.0 degrees ce	Isius junction
Test Data Docur	nent:
37695-619102 dr	awing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any spe	cification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type A	and Quantity:
3 uninsulated wir	e lead
Shelf Life:	
N/a	
Unit Of Measure	:
Demilitarization	
No	
Fiig:	
A110a0	